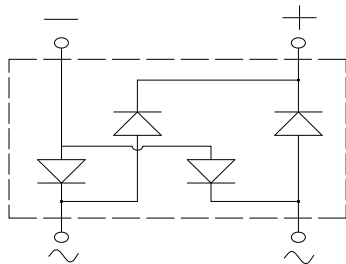
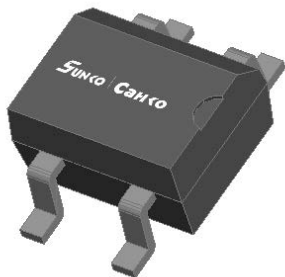


Bridge Rectifiers



Features

- UL recognition, file #E313149
- Ideal for automated placement
- Glass passivated chip junction
- High surge current capability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C

Typical Applications

General purpose use in AC/DC bridge full wave rectification for power supply, lighting ballast, battery charger, home appliances, office equipment, and telecommunication applications.

Mechanical Data

- **Package:** MBS
Molding compound meets UL 94 V-0 flammability rating, -
- **Terminals:** Tin plated leads, solderable per J-STD-002 and JESD22-B102
- **Polarity:** As marked on body

■ Maximum Ratings (T_a=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	HD1S	HD2S	HD4S	HD6S	HD8S	HD10S
Device marking code			HD1S	HD2S	HD4S	HD6S	HD8S	HD10S
Maximum Repetitive Peak Reverse Voltage	VRRM	V	100	200	400	600	800	1000
Maximum RMS Voltage	VRMS	V	70	140	280	420	560	700
Maximum DC blocking Voltage	VDC	V	100	200	400	600	800	1000
Average rectified output current @8.3ms sine wave, R-load, T _c =125°C	I _O	A	0.8					
Forward Surge Current (Non-repetitive) @8.3ms Half-sine wave, 1 cycle, T _j =25°C	I _{FSM}	A	25					
Current squared time @1ms≤t<8.3ms T _j =25°C, Rating of per diode	I ² t	A ² s	2.6					
Storage temperature	T _{stg}	°C	-55 ~ +150					
Junction temperature	T _j	°C	-55 ~ +150					

■ Electrical Characteristics (T_a=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	HD1S	HD2S	HD4S	HD6S	HD8S	HD10S
Maximum instantaneous forward voltage drop per diode	V _F	V	I _{FM} =0.4A	1.0					
Maximum DC reverse current at rated DC blocking voltage per diode	I _R	μA	T _j =25°C	5					
			T _j =125°C	50					
Typical junction capacitance	C _j	pF	Measured at 1MHz and Applied Reverse Voltage of 4.0 V.D.C	6					

HD1S THRU HD10S

■ Thermal Characteristics (T_a=25°C Unless otherwise specified)

PARAMETER		SYMBOL	UNIT	HD1S	HD2S	HD4S	HD6S	HD8S	HD10S
Typical Thermal Resistance	Between junction and ambient	R _{θJ-A}	°C/W	65.0					
	Between junction and lead	R _{θJ-L}		28.0					
	Between junction and case	R _{θJ-C}		20.0					

Note: Device mounted on P.C.B with 35mm*25mm*1.7mm.

■ Ordering Information (Example)

PREFERRED P/N	PACKING CODE	UNIT WEIGHT(g)	MINIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
HD1S ~ HD10S	F1	Approximate 0.12	2500	/	40000	13' reel
HD1S ~ HD10S	F2	Approximate 0.12	3000	/	48000	13' reel

■ Characteristics(Typical)

FIG1: I_o-T_c Curve

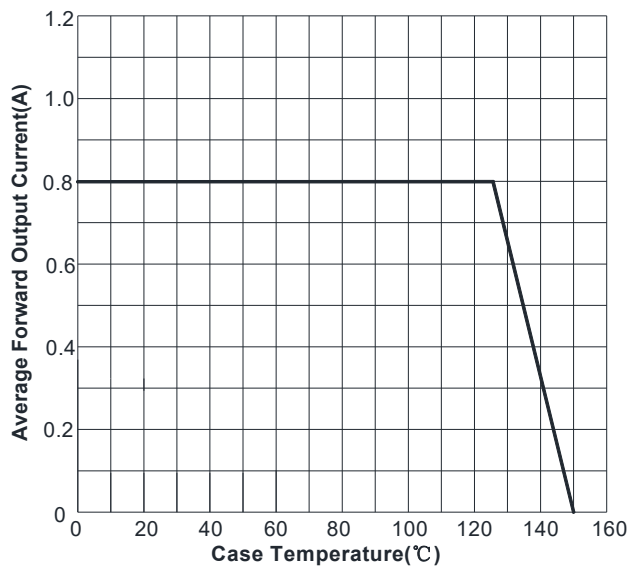


FIG2: Surge Forward Current Capability

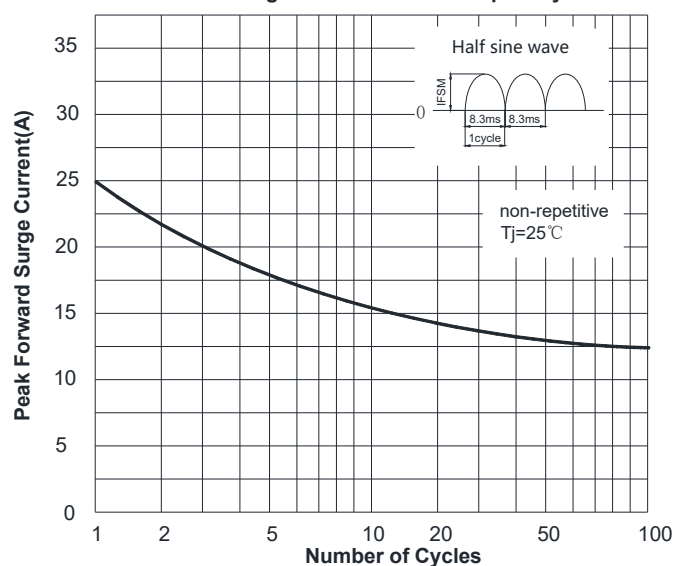


FIG3: Typical Forward Voltage

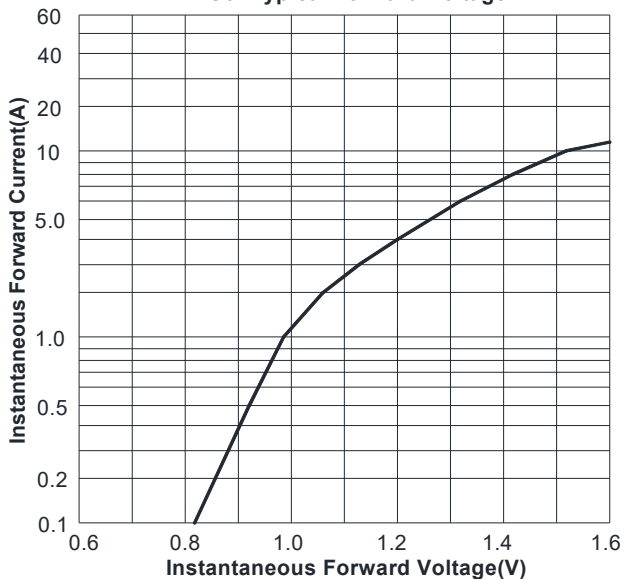
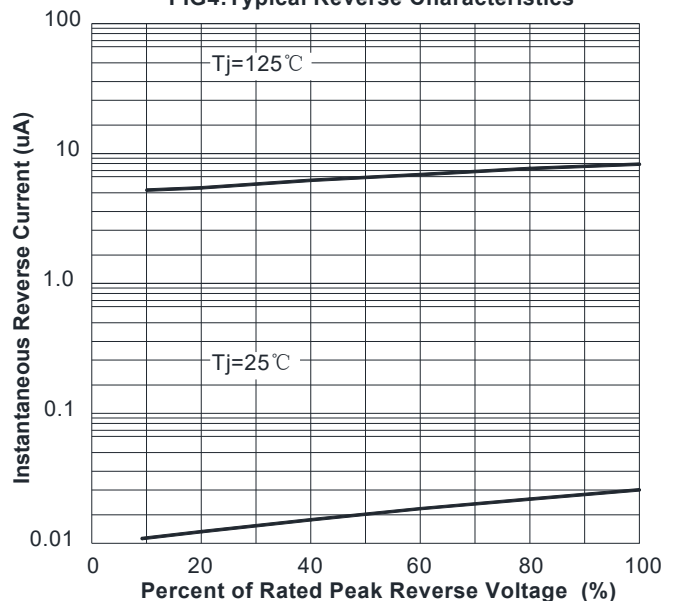
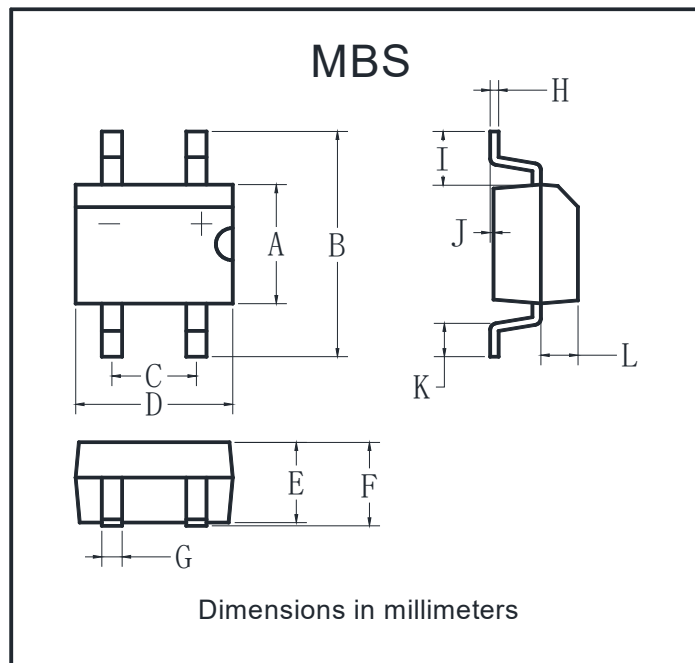


FIG4: Typical Reverse Characteristics

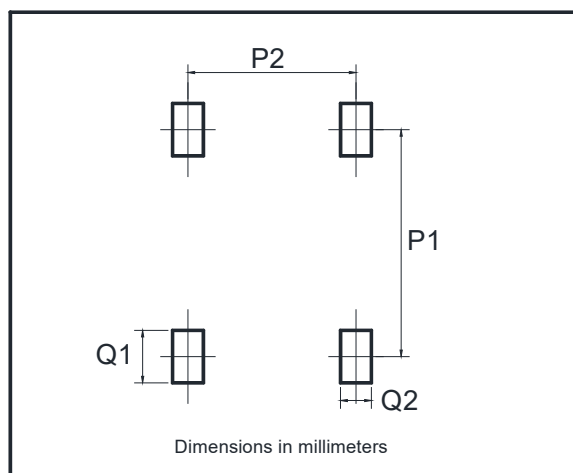


■ Outline Dimensions



MBS		
Dim	Min	Max
A	3.60	4.00
B	7.00 Max	
C	2.20	2.60
D	4.50	4.90
E	2.30	2.70
F	3.00 Max	
G	0.56	0.84
H	0.15	0.35
I	1.10	2.12
J	0.20 Max	
K	0.70	1.10
L	0.95	1.53

■ Suggested pad layout



Dim	Min
P1	6.00
P2	2.40
Q1	1.84
Q2	1.20

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